

**THIRD SEMESTER B.TECH (E & C) DEGREE END SEMESTER EXAMINATION  
NOV/DEC 2015**

**SUBJECT: ANALOG ELECTRONIC CIRCUITS (ECE - 201)**

**TIME: 3 HOURS**

**MAX. MARKS: 50**

**Instructions to candidates**

- Answer **ANY FIVE** full questions.
- Missing data may be suitably assumed.

- 1A. For the transistor circuit in Fig. Q1(A),  $V_{CC}=22.5V$ ,  $R_C=5.6k\Omega$ ,  $R_e=1k\Omega$ ,  $R_1=90k\Omega$ ,  $R_2=1k\Omega$ ,  $V_{BE} = 0.6V$ , and  $\beta=55$ , determine the Q-point.
- 1B. Given that  $R_b=9k\Omega$ ,  $R_e=1k\Omega$ ,  $\beta=55$  and  $V_{BE} = V+(R_b+R_e)[(1+\beta)/\beta]I_{CO}-[(R_b+R_e(1+\beta))/\beta]I_C$ . Assuming  $I_{CO}$  and  $\beta$  to be constant, determine the stability factor  $S'=\partial I_C/\partial V_{BE}$ .
- 1C. Explain to how to obtain  $h_{fe}$  from the transistor output characteristics. In the Fig. Q1(C), if  $i_{C2}=2mA$ ,  $i_{C1}=1mA$ ,  $i_{B2}=20\mu A$  and  $i_{B1}=10\mu A$ , determine the value of  $h_{fe}$ .

(5+3+2)

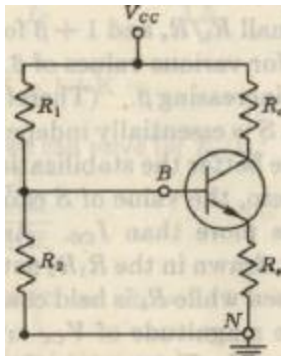


Fig. Q1(A)

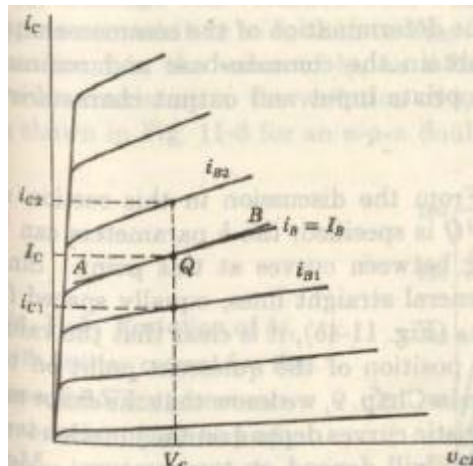


Fig. Q1(C)

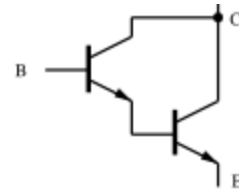


Fig. Q2(A)

- 2A. For the transistor circuit in Fig. Q2(A), two transistors are identical with  $h_{ie}=1k\Omega$  and  $h_{fe}=100$  and other parameters are neglected. If terminal C is connected to  $V_{CC}$ , a  $1k\Omega$  resistor is connected from E to ground, determine the small signal resistance seen at the terminal B.
- 2B. For the circuit drawn in Fig. Q2(B), obtain an expression for  $A_I=-I_L/I_1$ ,  $Z_I=V_1/I_1$  and  $A_V=V_2/V_1$ .
- 2C. For a transistor  $I_C=2mA$ ,  $V_T=26mV$  and  $h_{fe}=100$ . Verify if the following statements are true.
- For the transistor,  $g_m = I_C/V_T = 76.9mA/V$ .
  - For the transistor,  $r_{b'e} = h_{fe}/g_m = 1.3k\Omega$ .

(5+3+2)

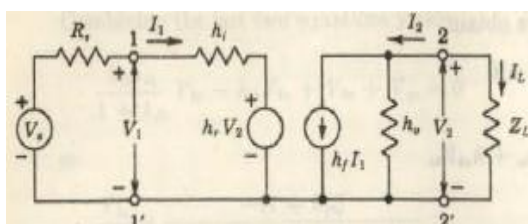


Fig. Q2(B)

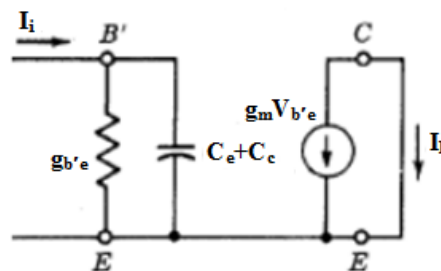


Fig. Q3(A)

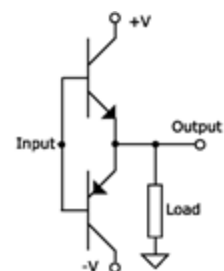


Fig. Q3(B)

- 3A. In the circuit of Fig. Q3(A), given that  $h_{fe}=50$ ,  $g_m = 50\text{mA/V}$ ,  $r_{be}=1\text{k}\Omega$ ,  $C_c=3\text{pF}$ ,  $C_e=100\text{pF}$ . i) Obtain an expression for  $A_i=I_L/I_i$ . ii) Calculate the Cut-off frequency of  $A_i$ , when it is written in the form  $|A_i|=h_{fe}/[1+(f/f_\beta)^2]^{1/2}$ .
- 3B. Assuming ideal transistor, show that the amplifier circuit in Fig. Q3(B), has a maximum efficiency of 78.5%.
- 3C. i) A single stage amplifier has a upper cut-off frequency of 2MHz. Three such stages are connected in cascade are non-interacting. The overall cut-off frequency will be \_\_\_\_.
- ii) In a device input current  $i_b$  and output current  $i_c$  are related by  $i_c=i_b+i_b^2$ . If the input current  $i_b=\cos(2\pi 100t)+\cos(2\pi 200t)$ , output current will be \_\_\_\_.

(5+3+2)

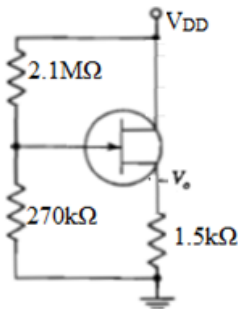


Fig. Q4(A)

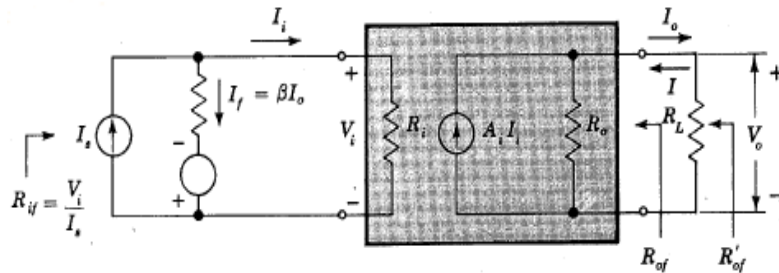


Fig. Q5(A)

- 4A. In the FET circuit of Fig. Q4(A), the device has  $g_m=25\text{mA/V}$ ,  $r_d=50\text{k}\Omega$ . If the input signal ( $V_i$ ) is at the gate terminal, Calculate the value of voltage gain ( $V_o/V_i$ ), resistance seen by the input source and the resistance seen at the output terminal.
- 4B. With necessary diagrams and I-V characteristics, explain the functioning of an n-channel MOSFET.
- 4C. Define  $\mu$  of an FET. Determine the value of  $\mu$  if an FET has  $g_m=25\text{mA/V}$ ,  $r_d=50\text{k}\Omega$ .

(5+3+2)

- 5A. By analyzing the amplifier block in Fig. Q5(A), show that,

$$A_I \equiv \frac{I_o}{I_i} = \frac{A_i R_o}{R_o + R_L}, \quad R_{if} = \frac{V_i}{(1 + \beta A_I) I_i} = \frac{R_i}{1 + \beta A_I}, \quad R_{of} = \frac{V}{I} = R_o(1 + \beta A_i), \quad R'_{of} = R'_o \frac{1 + \beta A_i}{1 + \beta A_I}$$

- 5B. Verify if the following statements made with respect to the circuit in Fig. Q5(B) are true or false.
- Is an example of a Current Shunt feedback
  - In the network drawn without feedback, on the input side  $15\text{k}\Omega$  and  $100\Omega$  resistors appear in series.
  - In the network drawn without feedback, on the output side  $15\text{k}\Omega$  and  $100\Omega$  resistors appear in parallel.
  - For small signal analysis,  $4.7\text{k}\Omega$ ,  $91\text{k}\Omega$  and  $10\text{k}\Omega$  appear from collector of Q1 to ground.
  - The  $1\text{k}\Omega$  resistor present at the emitter of Q1 will not appear in the small signal analysis due to large capacitance connected across it.

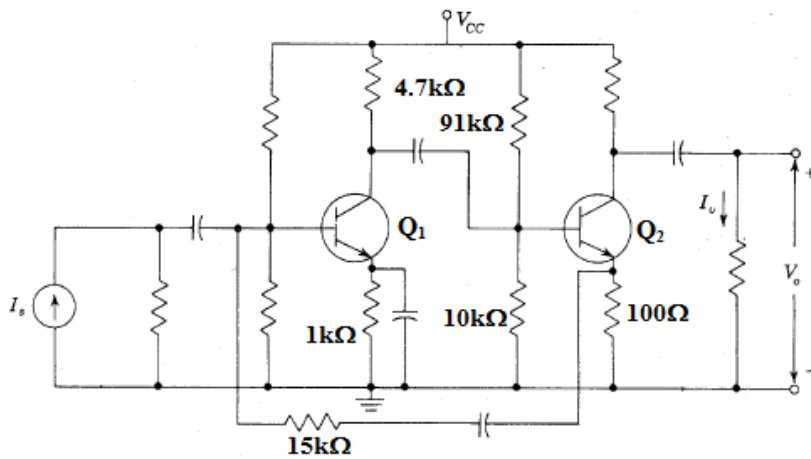


Fig. Q5(B)

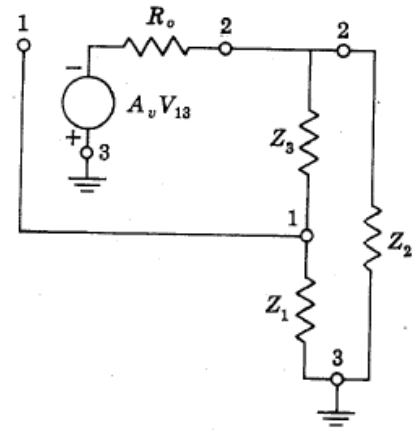


Fig. Q6(A)

- 6A. In the circuit of Fig. Q6(A), obtain an expression for loop gain  $-A\beta$ . If all 'Z' are reactive elements, for  $-A\beta$  to be unity and positive, show that  $Z_1$  and  $Z_2$  must have the same sign.
- 6B. Verify if the following statements are true or false.
1. In a Wien bridge oscillator, if  $R=1k\Omega$ , required to C to get a 10kHz oscillation is  $0.016\mu F$ .
  2. A crystal can be used as an inductor or as a capacitor depending on the frequency of operation.
  3. It is possible to build an oscillator circuit using an Opamp, 2 resistors and 2 capacitors.
  4. Sweep circuits are commonly used in CRTs.
  5. To get stable frequency of oscillation, crystal oscillators are preferred.

(5+5)